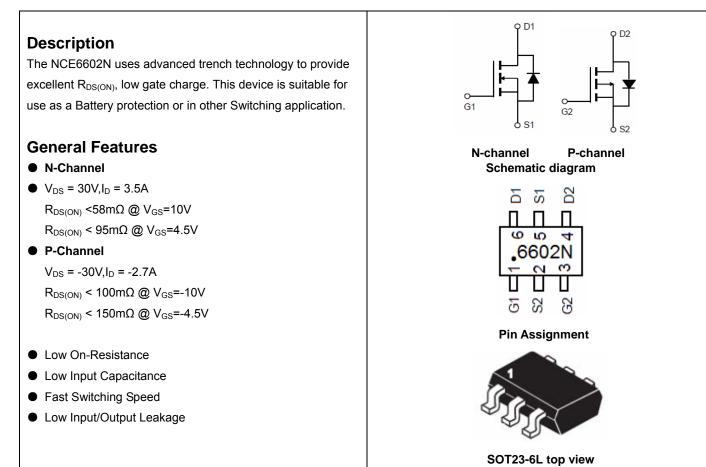


NCE N and P-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
6602N	NCE6602N	SOT23-6L	Ø180mm	8mm	3000 units

Absolute Maximum Ratings (T_A=25[°]Cunless otherwise noted)

Paramete	Symbol	N-Channel	P-Channel	Unit		
Drain-Source Voltage		V _{DS}	30	-30	V	
Gate-Source Voltage	V _{GS}	±20	±20	V		
Continuous Drain Current	T _A =25℃		3.5	-2.7	٨	
	T _A =70℃		3	-2.1	A	
Pulsed Drain Current ^(Note 1)		I _{DM}	20	-15	А	
Maximum Power Dissipation	T _A =25℃	PD	1.2		W	
Operating Junction and Storage Ter	T _J ,T _{STG}	-55 To 150	-55 To 150	°C		

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note2)	$R_{ extsf{ heta}JA}$	N-Ch	104	°C/W
Thermal Resistance, Junction-to-Ambient (Note2)	R _{0JA}	P-Ch	104	°C/W



N-CH Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·		•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	30	33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =250µA	1.2	1.5	2.2	V
Drain October Or Otata Davistance	P	V _{GS} =10V, I _D =3.5A	-	36	58	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =2A	-	60	95	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =3.1A	-	4	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}		-	251	-	PF
Output Capacitance	Coss	V _{DS} =15V,V _{GS} =0V, F=1.0MHz	-	38	-	PF
Reverse Transfer Capacitance	Crss		-	32	-	PF
Switching Characteristics (Note 4)	· ·		•			
Turn-on Delay Time	t _{d(on)}		-	4.5	-	nS
Turn-on Rise Time	tr	V_{DD} =15V, R _L =3 Ω	-	1.5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =6 Ω	-	18.5	-	nS
Turn-Off Fall Time	t _f		-	15.5	-	nS
Total Gate Charge	Qg		-	10.0	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =15V,I _D =3.5A,	-	1.9	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	1.8	-	nC
Drain-Source Diode Characteristics					•	
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =3.5A	-	0.8	1.2	V
Diode Forward Current (Note 2)	ا _S		-	-	3.5	А

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production



P-CH Electrical Characteristics (T_A=25°C unless otherwise noted)

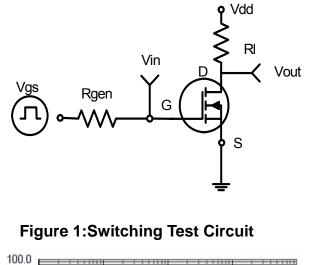
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-30	-33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	•					
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250µA	-1	-1.6	-2.5	V
Durin Course On Chata Desistence	D	V _{GS} =-10V, I _D =-2.7A	-	69	100	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-2A	-	110	150	mΩ
Forward Transconductance	g fs	V _{DS} =-10V,I _D =-2.7A		2	-	S
Dynamic Characteristics (Note4)						•
Input Capacitance	C _{lss}		-	278	-	PF
Output Capacitance	C _{oss}	- V _{DS} =-15V,V _{GS} =0V, F=1.0MHz	-	43	-	PF
Reverse Transfer Capacitance	Crss		-	35	-	PF
Switching Characteristics (Note 4)						•
Turn-on Delay Time	t _{d(on)}		-	8	-	nS
Turn-on Rise Time	tr	V _{DD} =-15V,R _L =15Ω	-	5	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =-10V,R _{GEN} =6Ω	-	12	-	nS
Turn-Off Fall Time	t _f		-	4	-	nS
Total Gate Charge	Qg		-	5.8	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-15V,I _D =-2.7A,V _{GS} =-10V	-	1	-	nC
Gate-Drain Charge	Q _{gd}]	-	1.1	-	nC
Drain-Source Diode Characteristics	•					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-2.7A	-	-	-1.2	V

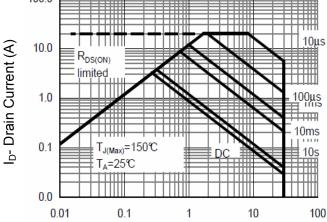
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production

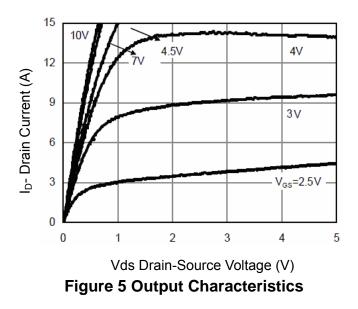


N- Channel Typical Electrical and Thermal Characteristics





Vds Drain-Source Voltage (V) Figure 3 Safe Operation Area



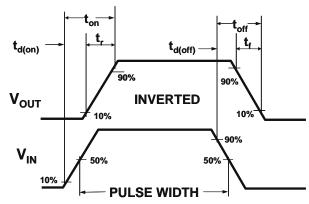


Figure 2:Switching Waveforms

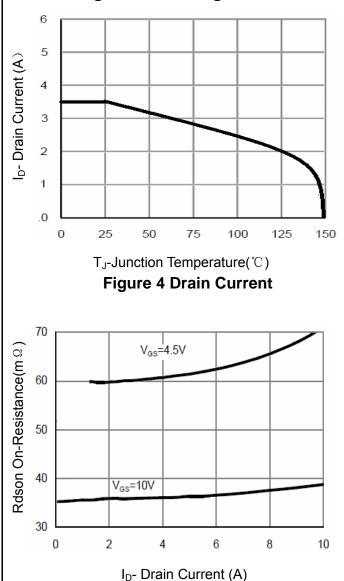
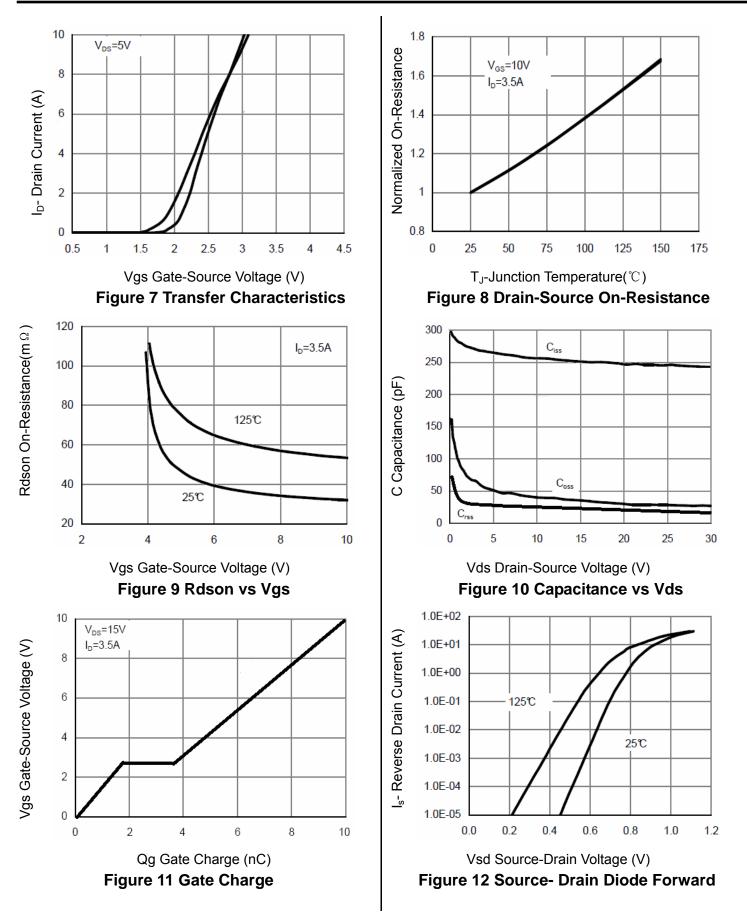


Figure 6 Drain-Source On-Resistance



NCE6602N





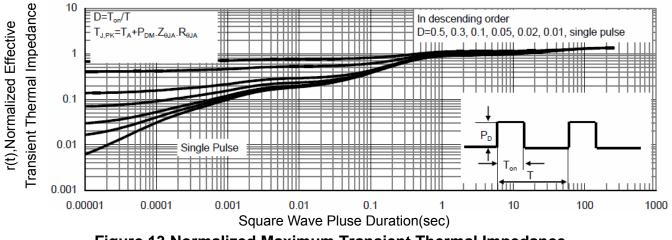
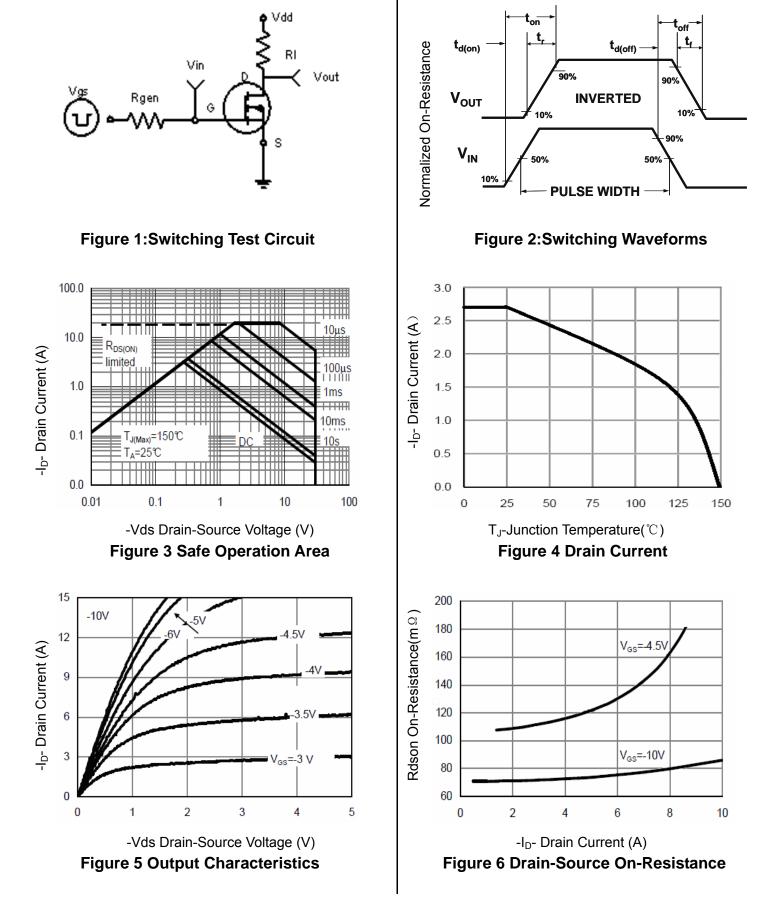


Figure 13 Normalized Maximum Transient Thermal Impedance

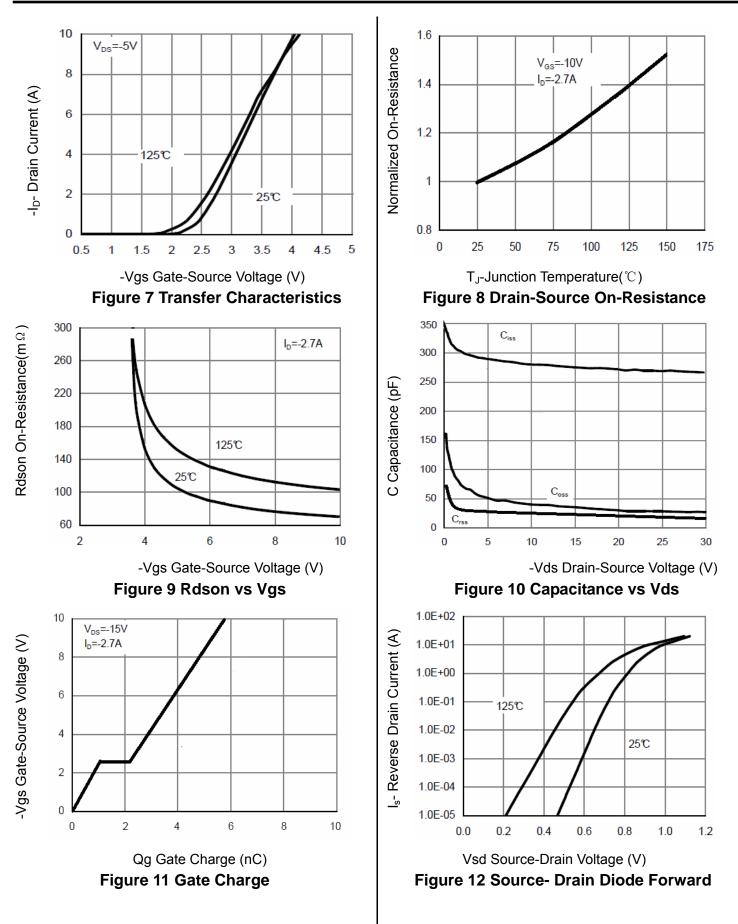


P- Channel Typical Electrical and Thermal Characteristics





NCE6602N





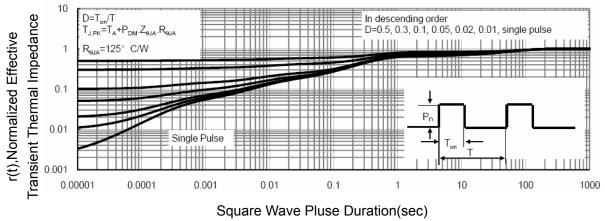
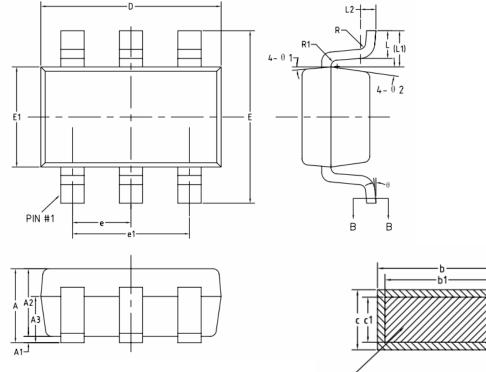


Figure 13 Normalized Maximum Transient Thermal Impedance



SOT23-6L Package Information



BASE METAL

SECTION B-B

COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX		
Α	-	-	1.45		
A1	0	-	0.15		
A2	0.90	1.10	1.30		
A3	0.60	0.65	0.70		
b	0.39	—	0.49		
Ь1	0.38	0.40	0.45		
с	0.12	-	0.19		
c1	0.11	0.13	0.15		
D	2.85	2.95	3.05		
E	2.60	2.80	3.00		
E1	1.55	1.65	1.75		
е	0.85	0.95	1.05		
e1	1.80	1.90	2.00		
L	0.35	0.45	0.60		
L1		0.59REF			
L2	0.25BSC				
R	0.05	-	-		
R1	0.05	-	0.20		
θ	0°	-	8'		
θ 1	8'	10 °	12'		
θ2	8'	10 °	12*		



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